



Thermalization-controlled electron transport

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Thermalization in nonlinear transport : An example of MIRO

MIRO at order $\mathcal{O}(P)$: P = microwave power

"quantum MIRO": $\sigma_{\rm osc} \propto \tau_{ee}/\tau ~(+\tau/4\tau_*)$

Dmitriev, Mirlin, Polyakov '03

Dmitriev, Vavilov, Aleiner, Mirlin, Polyakov '05

Khodas, Vavilov '08

Dmitriev, Khodas, Mirlin, Polyakov, Vavilov '09

"quasiclassical MIRO":
$$\sigma_{
m osc} \propto | au_{in}|/ au$$

Dmitriev, Mirlin, Polyakov '04

Review: Dmitriev, Mirlin, Polyakov, Zudov, Rev. Mod. Phys. '12

- τ_{ee} thermalization of electrons among themselves
- τ_{in} thermalization with the external bath
- au, au_* disorder-induced scattering

Thermalization-controlled linear transport

resistivity $ho = (m/e^2n) \times 1/\tau$ (Ohm's law) au – momentum relaxation

$$\rho = (m/e^2 n) \times 1/\tau_{ee} ?$$

 τ_{ee} – thermalization of electrons among themselves (by itself) momentum-energy conserving

(anomalously) slow thermalization \Rightarrow class of linear transport phenomena in which $\rho \propto 1/\tau_{ee}$

"thermalization-controlled transport": $\tau \rightarrow \tau_{ee}$

"disorder-controlled thermalization": $\tau \leftarrow \tau_{ee}$ also nontrivial, but different!

Disorder-controlled thermalization

• Most prominent example: Energy relaxation in a single-channel quantum wire

▷ Luttinger liquid with backscattering disorder (impurities)

Bagrets, Gornyi, Polyakov '08-'09

nonequilibrium functional bosonization, kinetic equations for plasmons and electrons

$${
m energy\ relaxation\ rate} \quad au_E^{-1} = au^{-1} \qquad T \gg 1/lpha^2 au$$

 $(\tau: ext{elastic scattering off disorder}, \ lpha: ext{interaction constant})$

interaction independent

up to a renormalization of the strength of disorder



double-step electron distribution function in the middle of a biased quantum wire

experiment (tunneling spectroscopy) on C nanotubes: Chen et al. '09

Thermalization-controlled transport

This talk \longrightarrow two examples:

• without disorder: Coulomb drag resistivity for a double quantum wire

• with disorder: interaction-induced resistivity of a single quantum wire with smooth inhomogeneities

Both examples are for single-channel 1D systems (nanowires) —in which the effect is the strongest

Dmitriev, Gornyi, Polyakov, PRB '12 and to be published

Semiconductor nanowires: $2D \rightarrow 1D$



- CEO, V-groove, ... nanowires
- Quantum-Hall line junctions
- Double quantum wires
- ...

Atomic-precision "cleaved-edge" single-channel GaAs wires at the intersection of two quantum wells



From Auslaender et al., Science '02



 $\begin{array}{l} {\rm Semiconductor\ nanowires:} \\ {\rm Mean\ free\ path\ } l\sim 10\,\mu{\rm m} \end{array}$

Semiconductor nanowires: $2D \rightarrow 1D$



longest $(L \sim \underline{1 \text{ cm}})$ single-channel

GaAs quantum wires

- CEO, V-groove, ... nanowires
- Quantum-Hall line junctions
- Double quantum wires
- ...

backscattering disorder = random interedge tunneling



1D barrier in 2D: Kang et al., Nature '00; Yang et al., PRL '04 L-shaped quantum wells: Grayson et al., APL '05, PRB '07

Mean free path in 1D controlled continuously by magnetic field

From Grayson et al., PRB '07

Semiconductor nanowires: $2D \rightarrow 1D$



From Auslaender et al., Science '05 barrier width $\sim 6 \text{ nm}$ wire width $\sim 20\text{--}30 \text{ nm}$

- CEO, V-groove, ... nanowires
- Quantum-Hall line junctions
- Double quantum wires
- . . .



From Laroche et al., Science '14 barrier width $\sim 15 \text{ nm}$ distance between the wires $\sim 35 \text{ nm}$

Coulomb drag: Current induced by current

Two conductors (quantum wells, quantum wires, ...) coupled by Coulomb interaction:



No tunneling between the wires, only coupling by e-e interactions

Coulomb drag = response of electrons in the passive conductor to a current in the active conductor, mediated by Coulomb interaction

Coulomb drag: Current induced by current

Two conductors (quantum wells, quantum wires, ...) coupled by Coulomb interaction:



No tunneling between the wires, only coupling by e-e interactions

Passive wire: no current if biased by V_2 to compensate for the drag

Transresistivity
$$ho_{\rm D} = -E_2/j_1$$
(response to j_1)Transconductivity $\sigma_{\rm D} = j_2/E_1$ (response to E_1)

Coulomb drag: Experiment

- Discovery 2D-2D: Gramila, Eisenstein, MacDonald, Pfeiffer & West, PRL '91
- **Prediction :** Pogrebinskii, Sov. Phys. Semicond. '77

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- "Orthodox theory": Zheng & MacDonald, PRB '93; Jauho & Smith, PRB '93 Kamenev & Oreg, PRB '95; Flensberg, Hu, Jauho & Kinaret, PRB '95
- Double-layer semiconductor structures : Sivan et al. '92; Kellogg et al. '02 Pillarisetty et al. '02-'05; Price et al. '07; Seamons et al. '09
- Drag in the QH regime : Rubel et al. '97; Lilly et al. '98 Kellogg et al. '02-'03; Tutuc et al. '09
- Oscillatory magnetodrag: Hill et al. '96; Feng et al. '98 Lok et al. '01; Muraki et al. '03
- Double graphene layers : *Kim et al. '11-'12; Gorbachev et al. '12 Titov et al. '13*
- Double quantum-point contacts: Khrapai et al. '07
- Double quantum wires : Debray et al. '00-'02; Yamamoto et al. '02-'06 Laroche et al. '11-'14

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Coulomb drag between quantum wires: Setup



Debray et al., JPCM '01



Yamamoto et al., Science '06 (Tarucha group)

planargeometry , GaAlAssoft barriers , width $\sim 80 \text{ nm}$ distance between the wires $d \sim 200 \text{ nm}$

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length \sim 4\,\mu{\rm m}
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Laroche et al., Nature Nanotech. '11, Science '14 (Gervais group)

vertical geometry, GaAlAshard barriers, width $\sim 15 \text{ nm}$ distance between the wires $d \sim 35 \text{ nm}$

Coulomb drag between quantum wires: Experiment



Laroche et al., Science '14

Drag effect up to 25% in closely packed nanowires on the 10 nm scale



Debray et al., JPCM '01



Yamamoto et al., Science '06

Coulomb drag: "Orthodox theory"

Zheng & MacDonald '93 Kamenev & Oreg '95; Flensberg, Hu, Jauho & Kinaret '95

$$\rho_{\rm D} = \frac{1}{e^2 n_1 n_2} \int \frac{d\omega}{2\pi} \int \frac{d^{\rm D}q}{(2\pi)^{\rm D}} \frac{(q^2/{\rm D})|V_{12}(\omega,q)|^2}{2T\sinh^2(\frac{\omega}{2T})} \ {\rm Im}\Pi_1(\omega,q) \ {\rm Im}\Pi_2(\omega,q)$$

 V_{12} – interwire (screened) interaction, $\Pi_{1,2}$ – density-density correlators

$$2{
m D}:~
ho_{
m D}\propto (T/\Lambda)^2~~\Lambda-{
m UV}~{
m cutoff}~({
m Fermi}~{
m energy})$$

"Golden rule approach" $(
ho_{
m D} \propto V_{12}^2)$

 $ho_{\rm D} = 0$ in a particle-hole symmetric $(\Lambda \to \infty)$ 2D system (electron drag current) = -(hole drag current)

Drag between clean quantum wires: Electron-hole symmetry

Nazarov & Averin '98

Klesse & Stern '00; Fiete, Le Hur & Balents '06

Golden rule in 1D Fermi liquid (linear dispersion): $ho_{\rm D} \sim g_1^2 \frac{h}{e^2} \frac{\Lambda}{v_F} \frac{T}{\Lambda}$ Hu & Flensberg '96

 g_1 – interwire e-e backscattering

Linearized dispersion in 1D: No drag due to forward scattering but backward scattering does contribute

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Linearized dispersion in 1D: No drag due to forward scattering but backward scattering does contribute

Luttinger-liquid renormalization: $ho_{
m D} \propto g_1^2 \, (T/\Lambda)^\kappa ~\kappa < 1$

"Pseudospin gap": $ho_{\mathrm{D}} \propto \exp(\Delta/T)$ T
ightarrow 0Zigzag CDW ordering $T \ll \Delta \sim (g_1)^{\frac{2}{1-\kappa}} \Lambda$ $\propto \exp\left(-\frac{4k_F d}{1-\kappa}\right)$

"Absolute drag" $(j_1 \simeq j_2)$ in long Luttinger constrictions

Drag between clean quantum wires: Curvature

Pustilnik, Mishchenko, Glazman & Andreev '03

Aristov '07; Rozhkov '08

Beyond the Luttinger model:

Nonlinear dispersion of the (bare) electron spectrum

$$ho_{
m D}\sim eta^2rac{h}{e^2}\,rac{\Lambda}{v_F}\left(rac{T}{\Lambda}
ight)^2 \propto k_F/m^2$$

 β – interwire e-e forward scattering



 $T \gg v_F/d ~~
ightarrow
ho_{
m D} = {
m const}(T)$

d – distance between the wires

$$T \ll eta \Lambda ~
ightarrow
ho_{
m D} \sim rac{1}{eta} rac{h}{e^2} rac{\Lambda}{v_F} \left(rac{T}{\Lambda}
ight)^5$$

Aristov '07

identical wires

strength of interwire backscattering $g_1^2 \propto \exp(-4k_F d)$

d - distance between the wires

- \implies for $k_F d \gg 1$, drag at not too low T
- \rightarrow by forward scattering with small-momentum transfer $\ll k_F$

Drag due to forward scattering

 $ho_{
m D}\simeta^2rac{h}{e^2}rac{T^2}{\epsilon_F v_F}$

obtained by means of:

Pustilnik, Mishchenko, Glazman & Andreev '03 Aristov '07; Rozhkov '08

Pustilnik et al.	\rightarrow	drift ansatz = "orthodox" formula
Aristov	\rightarrow	bosonization for large ω + "Loretzian ansatz"
Rozhkov	\rightarrow	bosonization/refermionization + "orthodox" formula

Drift ansatz : Electrons are at thermal equilibrium in the moving (with the drift velocity) frame

Drag due to forward scattering

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Drift ansatz : Electrons are at thermal equilibrium in the moving (with the drift velocity) frame

passive wire

$$egin{aligned} j_2 &= 0 &
ightarrow en_2 E_2 = \int rac{d\omega}{2\pi} \int rac{dq}{2\pi} \, q V_{12}(q) S_1(\omega,q) S_2(-\omega,-q) \ S_{1,2}(\omega,q) - ext{dynamic structure factors (intrawire int's incl.)} \ passive wire: & S_2(\omega,q) = S^{ ext{eq}}(\omega,q) &\leftarrow ext{equilibrium} \ active wire: & S_1(\omega,q) = S^{ ext{eq}}(\omega-qv_d,q) &\leftarrow ext{Galilean transform} \ + ext{FDT:} & S^{ ext{eq}}(\omega,q) = 2 ext{Im} \Pi(\omega,q)/(1-e^{-\omega/T}) &\longrightarrow ext{``orthodox''} \ formula \end{aligned}$$

Drag vs. thermalization

"Orthodox theory" \equiv electrons at equilibrium in the moving frame

> this (innocently looking) assumption is only justified for "perturbative" drag with $1/\tau_{\rm D} \ll 1/\tau_{\rm eq}$

 $1/ au_{
m D}$ – "drag rate" $ho_{
m D}=m/e^2n au_{
m D}$ (for $n_1=n_2=n$) $1/ au_{
m eq}$ – (smallest) thermalization rate

"Orthodox theory" \leftarrow totally wrong for forward scattering in 1D (right-left thermalization rate $1/\tau_{eq} = 0$)

In fact, for forward scattering
$$ho_{
m D}=0$$

No dc friction between chiral electrons!

Kinetic theory approach to drag

Quadratic dispersion: pair collisions in $1D \rightarrow$ momentum exchange

$$\delta_{\epsilon}\delta_{k} = rac{m}{|k-k'|} \left| \delta(k_{1}-k'_{2})\delta(k_{2}-k'_{1}) \right|$$

no change in the distribution function f(k) in a single wire

double wire : center-of-mass distribution $f_1(k) + f_2(k) = {
m const.}$

kinetic equation for the relative distribution $f_1(k) - f_2(k)$



Drag with small momentum transfer: Diffusion in energy space

 $T \gg v/d \rightarrow ext{Fokker-Planck}$ equation for the relative distribution $f_-(k)$:

current in momentum space $J = -D\partial_k f_- + f_-\partial_k D$

with the diffusion coefficient $D(k) \propto 1/\cosh^2[(k^2-k_F^2)/4mT]$



Drag with small-momentum transfer: Pair collisions

$$ho_{
m D} = rac{24\pi}{e^2 v_F au_{
m D}(\infty)} \left(rac{2\epsilon_F^3}{\pi T^3}
ight)^{1/2} e^{-2\epsilon_F/T}
onumber \ {
m for} \ v_F/d \ll T \ll \epsilon_F$$

Friction due to effective backscattering by diffusion in energy space through the point k = 0

No drag without R-L thermalization

For $T \ll v_F/d$: backscattering dominates with $1/ au_{
m D} \propto e^{-4k_F d}$

Thermalization in the moving or stationary frame: The difference matters!



$$g_-(k) \leftarrow ext{measure of nonequilibrium}: f_-(k) = f^T + g_-(k) T \partial_\epsilon f^T$$

In which frame the system chooses to thermalize (how strong drag is) depends crucially on intrawire equilibration (triple collisions) ! Enhancement of drag by intrawire thermalization

 $\mathcal{D}_2 \leftarrow \text{pair inter wire} \quad \mathcal{D}_3 \leftarrow \text{triple intra wire}$



 $(\mathcal{D}_3/\mathcal{D}_2 \text{ for fixed } \mathcal{D}_3) = (\text{distance between the wires})$

Plateau:
$$ho_{\mathrm{D}} = rac{4\pi\mathcal{D}_3}{e^2k_F} \left(rac{\epsilon_F}{\pi T^3}
ight)^{1/2} e^{-\epsilon_F/T} = rac{m}{e^2n} imes rac{1}{ au_{\mathrm{eq}}}$$

independent of \mathcal{D}_2 , i.e., the distance between the wires!

Coulomb drag in quantum wires : Temperature dependence



"orthodox theory" only for a large distance between the wires (solid line) right below ϵ_F

Activation (regime II): *independent of the distance between the wires*!

Interaction-induced resistivity of a quantum wire with smooth disorder

 \cdot smooth (for electrons) disorder \rightarrow negligeable backscattering on the Fermi level

 \cdot w/o e-e interactions \rightarrow zero-width Drude peak: dc ho=0

$$\sigma(\omega) = rac{e^2 v_F}{\pi} \left(1 - rac{3 \langle VV
angle_{q=0}}{2m^2 v_F^4}
ight) \delta(\omega) \ + rac{\langle VV
angle_{q=\omega/v_F}}{2\pi m^2 v_F^4}$$

 $\langle VV\rangle_q$ - correlator (at momentum q) of the random potential

• e-e interactions (amplitude α) \rightarrow golden-rule (high- ω) momentum relaxation rate (friction in the moving frame)

$$rac{1}{ au} = rac{lpha^2}{32k_F^4T} \int rac{dq}{2\pi} rac{q^4}{\sinh^2(v_Fq/4T)} \langle VV
angle_q$$

· dc ρ for pair collisions - ?

$$ho \propto e^{-\epsilon_F/T} \ll m/e^2 n au$$

effective backscattering due to diffusion in energy space

Interaction-induced resistivity of a quantum wire with smooth disorder

disorder-mediated pair collisions \rightarrow momentum relaxation diffusion coefficient (in energy space) D_2 + momentum-conserving triple collisions diffusion coefficient D_3

nonequilibrium part of the distribution function $g(k) \simeq g_{
m sf}(k) + g_{
m mf}(k)$

 $egin{aligned} g_{
m sf} \propto {
m sgn}(k) &\leftarrow ext{thermalization in the stationary frame} \ g_{
m mf} \propto k &\leftarrow ext{thermalization in the moving frame} \end{aligned}$

$$ho^{-1} \simeq
ho_{\mathrm{sf}}^{-1} +
ho_{\mathrm{mf}}^{-1}$$
 $ho_{\mathrm{sf}}^{-1} \sim e^2 n \epsilon_F rac{1}{D_2 + D_3} e^{\epsilon_F/T} \left(rac{T}{\epsilon_F}
ight)^{3/2}
ho_{\mathrm{mf}}^{-1} \sim e^2 n \epsilon_F rac{D_3 - D_2}{(D_2 + D_3)D_2}$

Interaction-induced resistivity of a quantum wire with smooth disorder

disorder-mediated pair collisions \rightarrow momentum relaxation diffusion coefficient (in energy space) D_2 + momentum-conserving triple collisions

diffusion coefficient D_3

$$egin{split}
ho \simeq m/e^2 n au_{ ext{eq}} \ D_2 \ll D_3 \ll D_2 \, e^{\epsilon_F/T} \left(rac{T}{\epsilon_F}
ight)^{3/2} \end{split}$$

 ρ independent of disorder!

see also Levchenko, Micklitz, Rech, Matveev '10

Summary

- Thermalization-controlled linear transport: Relaxation rate in Ohm's law \rightarrow thermalization rate $1/ au_{ee}$ $(
 ho = m/e^2n \, au_{ee})$
- Coulomb drag by small-momentum transfer between ballistic quantum wires:
 - "Orthodox" theory not valid
 - $\rho_{\rm D}$ independent of the strength of <u>inter</u>wirebut strongly dependent on the strength of <u>intra</u>wire interactions
- Resistivity of a smoothly-inhomogeneous quantum wire:
 - independent of the strength of disorder in the thermalization-controlled regime